

## N THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

Hsia, et al.

Serial No.: 09/955,677

Filed: September 19, 2001

For: Method and Apparatus for High-

Resolution In-Situ Plasma Etching of

**Inorganic and Metal Films** 

Art Unit: 2822

Examiner: Soward, Ida



## AMENDMENT AND RESPONSE TO ADVISORY ACTION

Mail Stop RCE Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir/Madam:

This is in response to the *Advisory Action* dated June 3, 2003 in the above-referenced patent application. Please enter and consider the following amendments and remarks in light of the attached *Request for Continued Examination* filed under 37 CFR §1.114 in the above-identified application.